

## INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## FCP125N65S3

## • FEATURES

- Drain Source Voltage-
  - : V<sub>DSS</sub>= 650V(Min)
- Static Drain-Source On-Resistance : R<sub>DS(on)</sub> = 125m Ω (Max)
- Fast Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

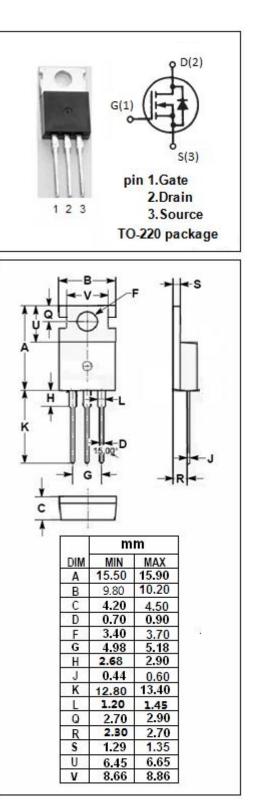
- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- AC and DC Motor Drives

## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	650	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
ID	Drain Current-Continuous	24	A
I <sub>DM</sub>	Drain Current-Single Plused	60	А
PD	Total Dissipation @T <sub>c</sub> =25°C	181	W
Tj	Max. Operating Junction Temperature	-55~150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.69	°C/W



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### • ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =1mA	650			V
VGS(th)	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 590uA	2.5		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 12A			125	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0			1	μA
Vsd	Diode Forward On-voltage	I <sub>F</sub> = 12A ;V <sub>GS</sub> = 0			1.2	V

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